

TECHNICAL DATASHEET

AVPR1100H56

The AVPR1100H56 is a 400W Solid State High Power Pulsed Amplifier. This amplifier module utilizes the latest high power RF LDMOS transistors and also features built in control and monitoring, with protection functions to ensure high availability. This amplifier is suitable for high power pulse applications or Radar system.

**Features**

- 1.025 GHz-1.150GHz frequency range
- Psat 56dBm type
- Power gain 56dB
- 50 ohm input/output impedance
- Built-in control, monitoring and protection circuits
- Solid-state Class AB design
- High Pulse Definition
- Suitable for pulse applications or Radar system
- Small and lightweight
- High reliability and ruggedness

**ELECTRICAL SPECIFICATIONS(T=25 °C,DC Voltage=50V,PW=100us,DC=10%,50Ω System)**

Description	Symbol	Min	Typ	Max	Unit
Operating Frequency	BW	1.025		1.150	GHz
Output Power	PPK	400	450		W
Pulse Width	PW	10		200	us
Duty Cycle	DC	1		15	%
Input Power for Rated PSAT	P <sub>IN</sub>		0		dBm
Harmonics @ Pout =300W	2 <sup>nd</sup>		-40	-35	dBc
Spurious Signals@ Pout =400W	Spur		-60		dBc
Input Return Loss	S11		-25	-15	dB
Rise /Fall time(Pulse Performance)	TRISE/FALL/OFF(10-90)		50		ns
Power droop	Droop		0.6	1	dB
Operating Voltage	VDC	48	50	52	V
Peak Current Consumption @ Pout =400W	IDD		10	13	A
Average Current Consumption @ Pout =400W	IDD		2.7	3	Amp
Switching Time @ 1kHz TTL, P <sub>IN</sub> = 0dBm	TON/TOFF		1	2	μs

**PROTECTION AND WARNING FUNCTION**

- Over threshold of duty cycle (High duty cycle)
- Over threshold of current
- Over threshold of temperature

Datasheet: REV A.2/ 01.20.2021

Unique Amplifier With Innovation

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**MECHANICAL SPECIFICATIONS**

Cooling External Heat Sink Needed (Not Supplied)

Length*Width*Height[ mm ]	200*150*30
Weight[ Kg ]	1.6
RF Connector Input	Type SMA, Female
RF Connector Output	Type N, Female

**ENVIRONMENTAL SPECIFICATIONS (Design to Meet)**

Module Operation Temperature	-20	65	°C
Storage Temperature Range	-25	70	°C
Relative-Humidity	N/A		
Altitude	N/A		
Vibration/Shock	N/A		

**LIMITS**

Input RF drive level without damage	$P_{in} \leq 10$	dBm
Load VSWR @ POUT =400W	$VSWR \leq 5:1$	N/A
Thermal Degradation	90	°C

**DC INTERFACE CONNECTOR –[D-Sub 7W2, Male]**

Pin #	Description	Specifications
A1	GND	Ground
A2	VDD	50VDC
1	CURRENT SENSE	Analog voltage relative to IDD @ 100mV per Ampere
2	TEMP SENSE	Analog voltage relative to Module's Temperature @ 10 mV/°C
3	ENABLE	Amplifier Enable: TTL Logic High (3.3V) (Internally Pulled-Low)
4	GND	Ground
5	N/C	No Connection

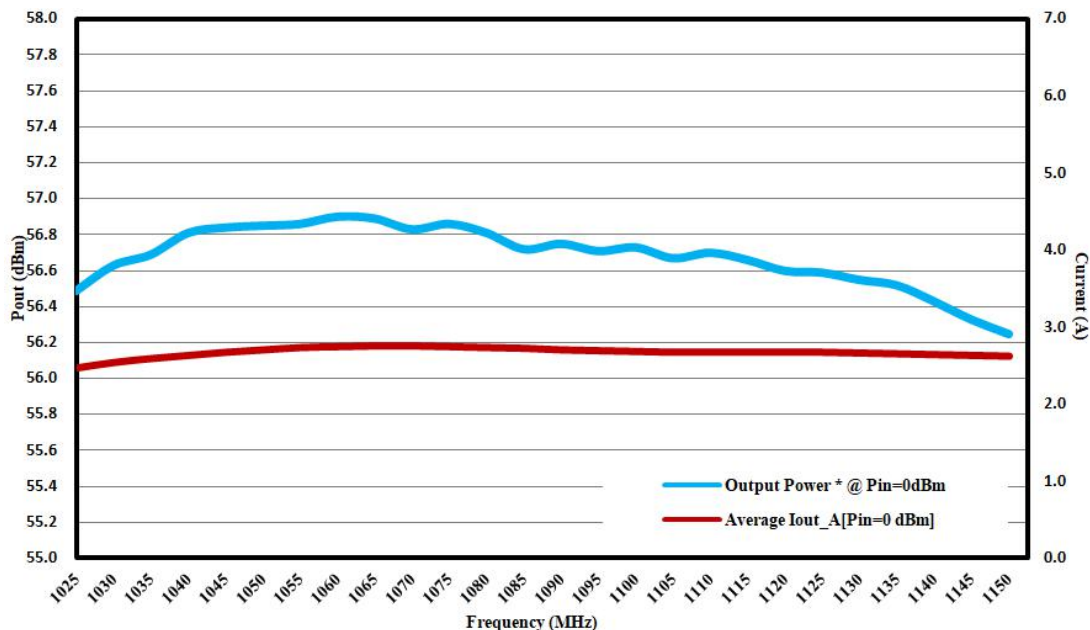
**PLOTTED AND OTHER DATA**

Notes:

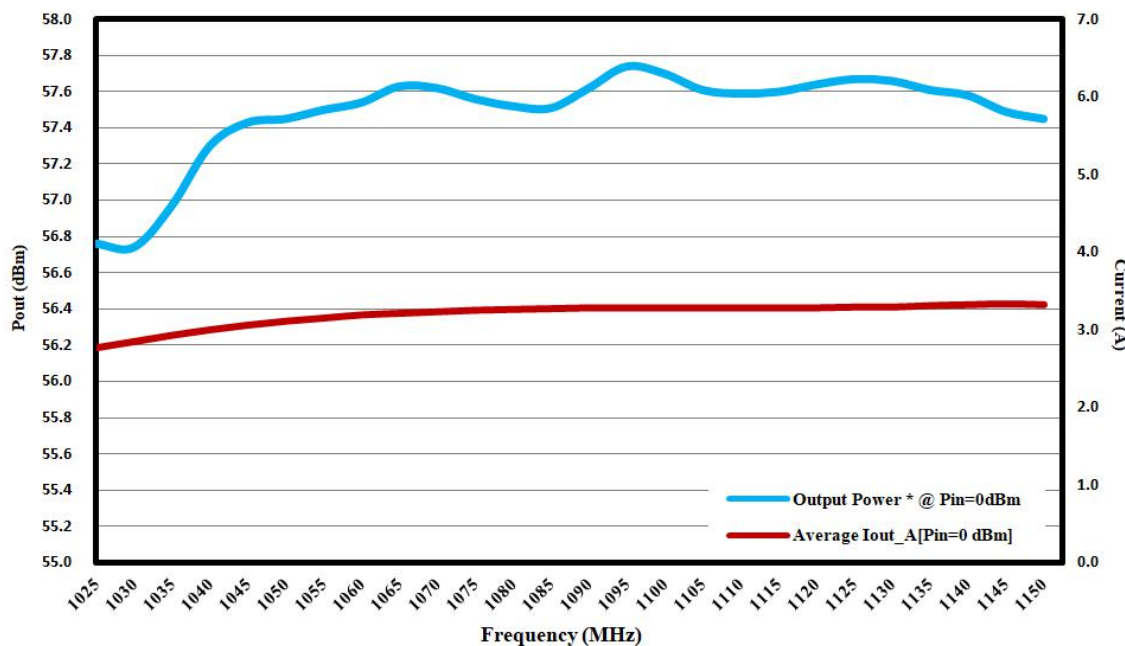
1. Values at +25°C, sea level.
2. ESD Sensitive Material. Handle only in approved ESD Workstation.
3. Heat Sink required for Proper Operation, Unit is cooled by conduction to heat sink.

TYPICAL PERFORMANCE DATA

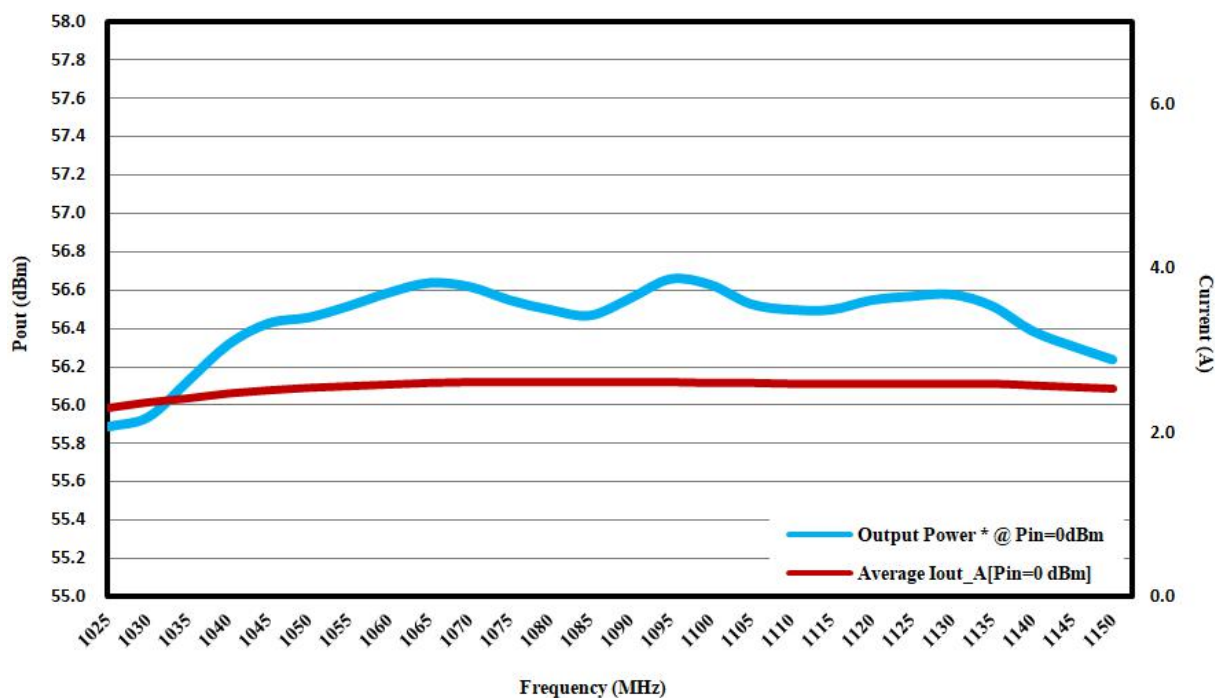
Pout & IDC [Pin=0dBm Ambient Temp= 25°C, VSWR<1.2, Duty Cycle=10%,Pulse Width=100uS ]



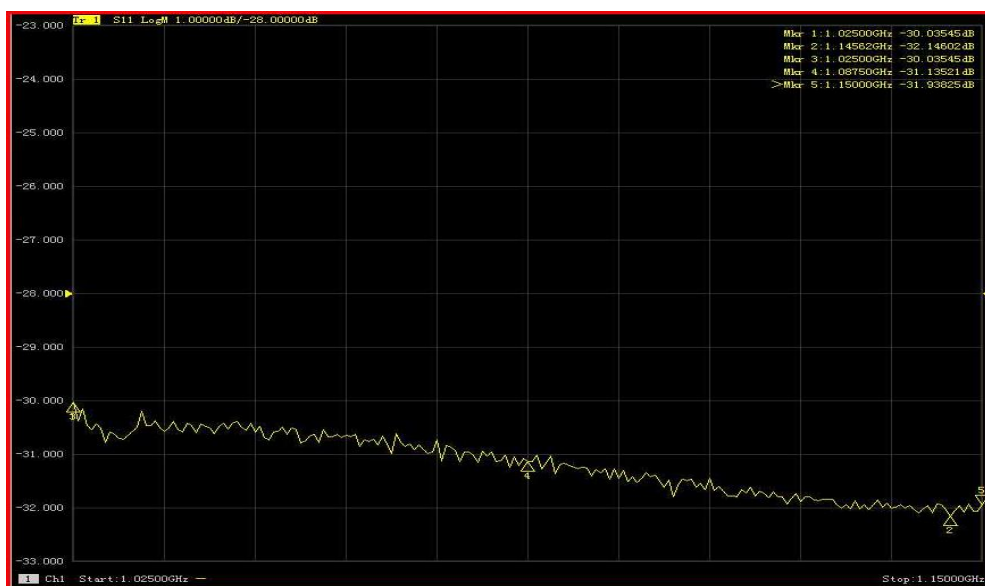
Pout & IDC [Pin=0dBm Ambient Temp= -20°C, VSWR<1.2, Duty Cycle=10%,Pulse Width=100uS ]



Pout & IDC [Pin=0dBm Ambient Temp= +65°C, VSWR<1.2, Duty Cycle=10%,Pulse Width=100uS ]



Small Signal S11 [Pin= -30dBm, Ambient Temp= 25°C, VSWR<1.2, Duty Cycle=10%,Pulse Width=100uS ]



OUTLINE DRAWING (mm)

